

Switch-Mode Power Supplies

Voltage and Current Sensing

Alarms, Detectors, and Sensors

D (SOIC) OR PW (TSSOP) PACKAGE (TOP VIEW)

COMF

16 40UT

15 4IN-

14] 4IN+

13 V<sub>cc-</sub>

12 3IN+

11 3IN-

10 30UT

9 CATHODE

Power-Good, Overvoltage, Undervoltage,

APPLICATIONS

10UT 11

1IN-

1IN+ 3

 $V_{cc+}$  4

2IN+ 5

2IN-[6

20UT 7

V<sub>REF</sub> [8

**Battery Chargers** 

**Overcurrent Detection** 

**Window Comparators** 

сомр

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### FEATURES

- OPERATIONAL AMPLIFIERS
  - Low Supply Current...200 µA/A
  - Medium Speed…2.1 MHz
  - Low-Level Output Voltage Close to  $V_{CC-}$ ...0.1 V Typ (R<sub>L</sub> = 10 k $\Omega$ )
  - Input Common-Mode Voltage Range Includes Ground
- COMPARATORS
  - Low Supply Current...200  $\mu$ A/A (V<sub>CC</sub> = 5 V)
  - Input Common-Mode Voltage Range Includes Ground
  - Low Output Saturation Voltage...
    Typically 250 mV (I<sub>sink</sub> = 4 mA)
- VOLTAGE REFERENCE
  - Adjustable Output Voltage...V<sub>REF</sub> to 36 V
  - Sink Current Capability...1 mA to 100 mA
  - 0.4% (A Grade) and 1% (Standard Grade)
    Precision
  - Latch-Up Immunity

## **DESCRIPTION/ORDERING INFORMATION**

The TSM102 and TMS102A combine the building blocks of a dual operational amplifier, a dual comparator, and a precision voltage reference, all of which often are used to implement a wide variety of power-management functions, including overcurrent detection, undervoltage/overvoltage detection, power-good detection, window comparators, error amplifiers, etc. Additional applications include alarm and detector/sensor applications.

The TSM102A offers a tight V<sub>REF</sub> tolerance of 0.4% at 25°C. The TSM102 and TSM102A are characterized for operation from  $-40^{\circ}$ C to 85°C.

ORDERING INFO	RMATION

T <sub>A</sub>	MAX V <sub>REF</sub> TOLERANCE (25°C)	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING
		SOIC – D	Tube of 75	TSM102AID	TSM102AI
	A grade:	50IC - D	Reel of 2500	TSM102AIDR	TSIMTUZAI
	0.4% precision	TSSOP – PW	Tube of 90	TSM102AIPW	SN102AI
–40°C to 85°C			Reel of 2000	TSM102AIPWR	SINTUZAI
-40°C 10 85°C		SOIC – D	Tube of 75	TSM102ID	TOMAGO
	Standard grade:	50IC - D	Reel of 2500	TSM102IDR	TSM102I
	1% precision	TSSOP – PW	Tube of 90	TSM102IPW	SN14021
		1350P - PW	Reel of 2000	TSM102IPWR	- SN102I

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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#### Absolute Maximum Ratings<sup>(1)</sup>

over free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage			36	V
$V_{ID}$	Input differential voltage		36	V	
VI	Input voltage range	-0.3	36	V	
I <sub>KA</sub>	Voltage reference cathode current		100	mA	
0	Backage thermal impedance (2)(3)	D package		73	°C/W
$\theta_{JA}$	Package thermal impedance <sup>(2)(3)</sup>	PW package		108	-C/W
TJ	Maximum junction temperature			150	°C
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Maximum power dissipation is a function of T<sub>J</sub>(max), θ<sub>JA</sub>, and T<sub>A</sub>. The maximum allowable power dissipation at any allowable ambient temperature is P<sub>D</sub> = (T<sub>J</sub>(max) - T<sub>A</sub>)/θ<sub>JA</sub>. Selecting the maximum of 150°C can affect reliability.
 (3) The package thermal impedance is calculated in accordance with JESD 51-7.

#### **Recommended Operating Conditions**

		MIN	MAX	UNIT
$V_{CC+} - V_{CC-}$	Supply voltage	3	30	V
V <sub>ID</sub>	Comparator differential input voltage		$V_{CC+} - V_{CC-}$	V
V <sub>KA</sub>	Cathode-to-anode voltage	V <sub>REF</sub>	36	V
Ι <sub>K</sub>	Reference cathode current	1	100	mA
T <sub>A</sub>	Operating free-air temperature	-40	85	°C

#### **Total Device Electrical Characteristics**

	PARAMETER	TEST CONDITIONS	T <sub>A</sub>	MIN	TYP	MAX	UNIT
	Total supply current,	V = 5 V V = 0 V No load	25°C		0.8	1.5	<b>m</b> A
ICC	excluding reference cathode current	$V_{CC+} = 5 V, V_{CC-} = 0 V, No load$	Full range			2	mA

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## **Operational Amplifier Electrical Characteristics**

 $V_{\rm CC+}$  = 5 V,  $V_{\rm CC-}$  = GND, R1 connected to  $V_{\rm CC}/2$  (unless otherwise noted)

	PARAMETER	TEST CONDITIO	NS	T <sub>A</sub>	MIN	TYP	MAX	UNIT
V	Input offect voltage			25°C		1	4.5	mV
V <sub>IO</sub>	Input offset voltage			Full range			6.5	mv
$\alpha V_{IO}$	Input offset voltage drift			25°C		10		μV/°C
	Input offect ourrent			25°C		5	20	nA
I <sub>IO</sub>	Input offset current			Full range			40	ПА
	Input biog gurrent			25°C		20	100	~ ^
I <sub>IB</sub>	Input bias current			Full range			200	nA
^		V <sub>CC+</sub> = 30 V, R1 = 10 kΩ,		25°C	50	100		V/mV
A <sub>VD</sub>	Large-signal voltage gain	$V_0 = 5 V \text{ to } 25 V$		Full range	25			V/IIIV
k <sub>SVR</sub>	Supply-voltage rejection ratio	$V_{CC+} = 5 V \text{ to } 30 V$		25°C	80	100		dB
	Input common mode voltage			25°C	V <sub>CC-</sub>		V <sub>CC+</sub> – 1.8	V
VICM	Input common-mode voltage		Full range	V <sub>CC-</sub>		V <sub>CC+</sub> – 2.2	v	
CMRR	Common-mode rejection ratio	$V_{CC+} = 30 \text{ V},$ $V_{ICM} = 0 \text{ V to } V_{CC+} - 1.8 \text{ V}$		25°C	70	90		dB
	Chart circuit ourrent		Source	25°C	3	6		~ ^
I <sub>SC</sub>	Short-circuit current	$V_{ID} = \pm 1 V, V_{O} = 2.5 V$	Sink	25 C	3	6		mA
V	Lligh lovel output veltage	V 20 V D 10 k0		25°C	27	28		V
V <sub>OH</sub>	High-level output voltage	$V_{CC+} = 30 \text{ V}, \text{ R}_{L} = 10 \text{ k}\Omega$		Full range	26			v
V		D 10 k0		25°C		130	170	mV
V <sub>OL</sub>	Low-level output voltage	$R_L = 10 \ k\Omega$		Full range			200	mv
SR	Slew rate	$ \begin{array}{c} V_{CC} = \pm 15 \ \text{V}, \ C_L = 100 \ \text{pF}, \\ V_I = \pm 10 \ \text{V}, \ R_L = 10 \ \text{k}\Omega \end{array} $		25°C	1.3	2		V/µs
GBW	Gain bandwidth product	$R_L = 10 \text{ k}\Omega, C_L = 100 \text{ pF}, \text{ f}$	25°C	1.4	2.1		MHz	
Φm	Phase margin	$R_L = 10 \text{ k}\Omega, C_L = 100 \text{ pF}$		25°C		45		0
THD	Total harmonic distortion			25°C		0.01		%
Vn	Equivalent input noise voltage	f = 1 kHz		25°C		19		nV/√Hz



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#### **Comparator Electrical Characteristics**

 $V_{CC+} = 5 V, V_{CC-} = GND$  (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	T <sub>A</sub>	MIN	TYP	MAX	UNIT	
V	Input offset voltage		25°C			5	mV	
V <sub>IO</sub>	input onset voltage		Full range			9	mv	
V <sub>ID</sub>	Comparator differential input voltage		Full range			V <sub>CC+</sub>	V	
1	Input offect ourrent		25°C		50		nA	
I <sub>IO</sub>	Input offset current		Full range			150	ΠA	
1	Innut high ourrent		25°C			250	~ ^	
I <sub>IB</sub>	Input bias current		Full range			400	nA	
	Ligh lovel output ourrest	V 1VV V 20V	25°C		0.1		nA	
I <sub>OH</sub> High-level output current		$V_{ID} = 1 V, V_{CC} = V_{O} = 30 V$	Full range			1	μΑ	
V					250	400	mV	
V <sub>OL</sub>	Low-level output voltage	$V_{ID} = -1 V$ , $I_{sink} = 4 mA$	Full range			700	mv	
A <sub>VD</sub>	Large-signal voltage gain	$V_{CC+} = 15$ V, R1 = 15 kΩ, V <sub>O</sub> = 1 V to 11 V	25°C		200		V/mV	
I <sub>sink</sub>	Output sink current	$V_{O} = 1.5 \text{ V}, V_{ID} = -1 \text{ V}$	25°C	6	16		mA	
M	Input common-mode		25°C	0		V <sub>CC+</sub> – 1.5	V	
V <sub>ICM</sub>	voltage range		Full range	0		$V_{CC+} - 2$	v	
t <sub>RESP</sub>	Response time <sup>(1)</sup>	R1 = 5.1 k $\Omega$ to V <sub>CC+</sub> , V <sub>REF</sub> = 1.4 V	25°C		1.3		μs	
t <sub>RESP,large</sub>	Large-signal response time	R1 = 5.1 kΩ to V <sub>CC+</sub> , V <sub>REF</sub> = 1.4 V, V <sub>I</sub> = TTL	25°C		300		ns	

(1) The response-time specification is for 100-mV input step with 5-mV overdrive. For larger overdrive signals, 300 ns can be obtained.

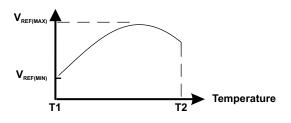
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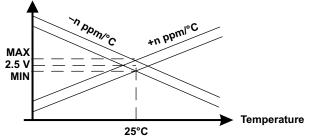
#### **Voltage-Reference Electrical Characteristics**

	PARAMETER		TEST CONDITIONS	T <sub>A</sub>	MIN	TYP	MAX	UNIT
V	Poforonoo voltago <sup>(1)</sup>	TSM102	$V_{KA} = V_{REF}, I_K = 10 \text{ mA},$	25°C	2.475	2.475 2.5 2.525		V
V <sub>REF</sub>	Reference voltage <sup>(1)</sup> TSM102A		See Figure 1	25°C	2.49	2.5	2.51	v
$\Delta V_{REF}$	Reference input voltage deviation over temperature range <sup>(1)</sup>		$V_{KA} = V_{REF}$ , $I_K = 10$ mA, See Figure 1	Full range		7	30	mV
	Average temperature coefficient of reference input voltage <sup>(2)</sup>		$V_{KA} = V_{REF}$ , $I_K = 10 \text{ mA}$	Full range		±22	±100	ppm/°C
V <sub>REF</sub> V <sub>KA</sub>	Ratio of change in reference voltage to change in cathode voltage		$V_{KA} = 3 V \text{ to } 36 V, I_K = 10 \text{ mA},$ See Figure 2	25°C		-1.1	-2	mV/V
	Defenses insut summer		$I_{K} = 10 \text{ mA}, \text{R1} = 10 \text{ k}\Omega, \text{R2} = \infty,$	25°C		1.5	2.5	
I <sub>REF</sub>	Reference input current		See Figure 2	Full range			3	μA
$\Delta I_{REF}$	Reference input current deviation over temperature range		$I_{K}$ = 10 mA, R1 = 10 k $\Omega$ , R2 = $\infty$ , See Figure 2	Full range		0.5	1	μΑ
I <sub>min</sub>	Minimum cathode current for regulation		V <sub>KA</sub> = V <sub>REF</sub> , See Figure 1	25°C		0.5	1	mA
I <sub>K,OFF</sub>	Off-state cathode current		See Figure 3	25°C		180	500	nA

ΔV<sub>REF</sub> is defined as the difference between the maximum and minimum values obtained over the full temperature range. ΔV<sub>REF</sub> = V<sub>REF(MAX)</sub> - V<sub>REF(MIN)</sub>
 The temperature coefficient is defined as the slopes (positive and negative) of the voltage vs temperature limits within which the

reference voltage is specified.





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#### PARAMETER MEASUREMENT INFORMATION

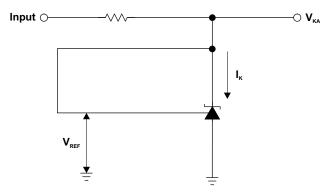


Figure 1. Test Circuit for  $V_{KA} = V_{REF}$ 

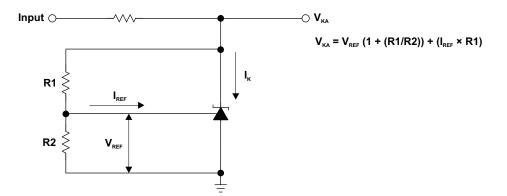


Figure 2. Test Circuit for  $V_{KA} > V_{REF}$ 

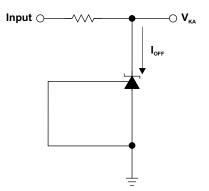


Figure 3. Test Circuit for I<sub>OFF</sub>



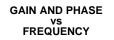
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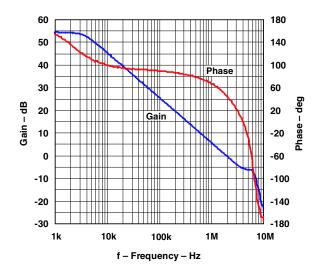
#### **TYPICAL CHARACTERISTICS**

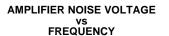
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AMPLIFIER TOTAL HARMONIC DISTORTION

#### Figure 4.







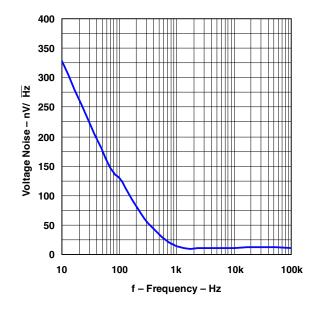


Figure 5.

V<sub>REF</sub> STABILITY VS CAPACITANCE

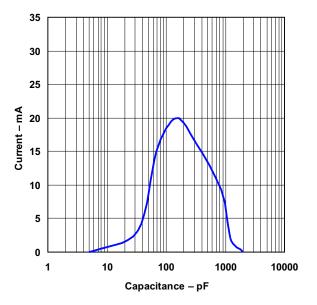


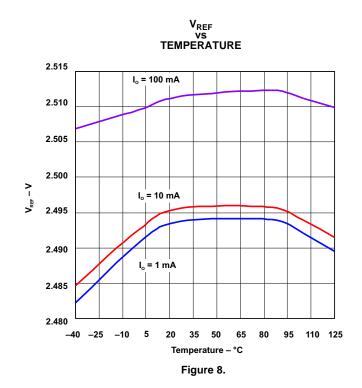
Figure 7.

Figure 6.

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## **TYPICAL CHARACTERISTICS (continued)**



Y TEXAS NSTRUMENTS www.ti.com

24-May-2007

#### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TSM102AID	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TSM102AIDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TSM102AIDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TSM102AIDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TSM102AIPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TSM102AIPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TSM102AIPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TSM102AIPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TSM102ID	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TSM102IDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TSM102IDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TSM102IDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TSM102IPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TSM102IPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TSM102IPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TSM102IPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)



<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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## TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TSM102AIDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TSM102AIPWR	TSSOP	PW	16	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1
TSM102IDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TSM102IPWR	TSSOP	PW	16	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1



## PACKAGE MATERIALS INFORMATION

11-Mar-2008



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TSM102AIDR	SOIC	D	16	2500	346.0	346.0	33.0
TSM102AIPWR	TSSOP	PW	16	2000	346.0	346.0	29.0
TSM102IDR	SOIC	D	16	2500	346.0	346.0	33.0
TSM102IPWR	TSSOP	PW	16	2000	346.0	346.0	29.0

## **MECHANICAL DATA**

MTSS001C - JANUARY 1995 - REVISED FEBRUARY 1999

## PW (R-PDSO-G\*\*)

#### PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.

Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.

E. Reference JEDEC MS-012 variation AC.



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